

Inventor(s): Andrew J. WALKER et al. DOCKET NO.: 035905-0103

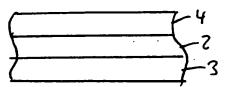


FIGURE 1

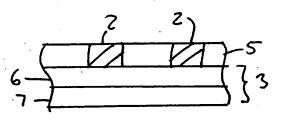


FIGURE 2A

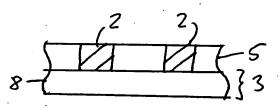


FIGURE 2B

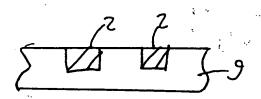


FIGURE 3

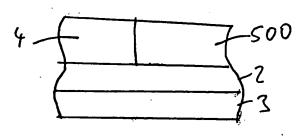
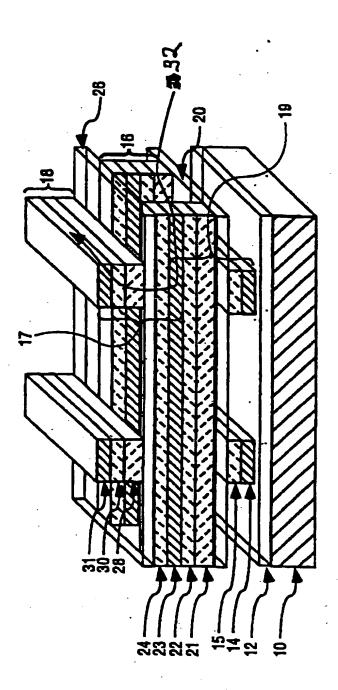


FIGURE 15

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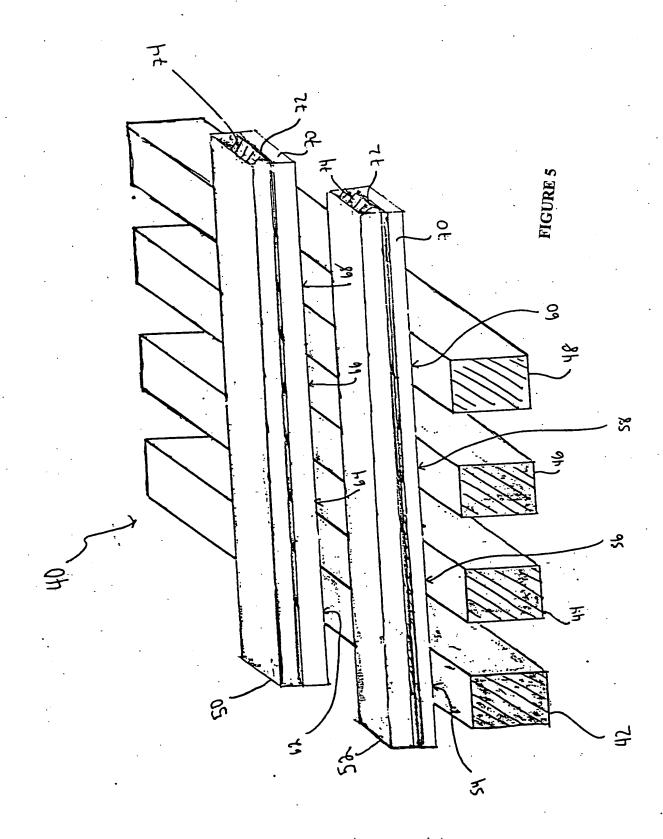
IGURE 4A

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				•		- \
	P+			139		_]
	CONDUCTOR			<u>140</u>		- 122
	P+			142		_
	ANTIFUSE			143		_丿
144	N-	~133		N-		
	N+	~132	141~	N+	121	
	CONDUCTOR	~131		CONDUCTOR		
	N+	~130		N+		•
	N	~129		N-		_ <
ANTIFUSE 128						
P+				127		_ _ 120
CONDUCTOR 126						_
· :		P+	-	125		_丿

FIGURE 4B

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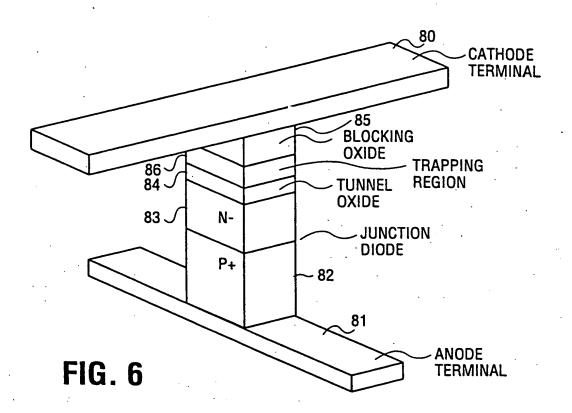


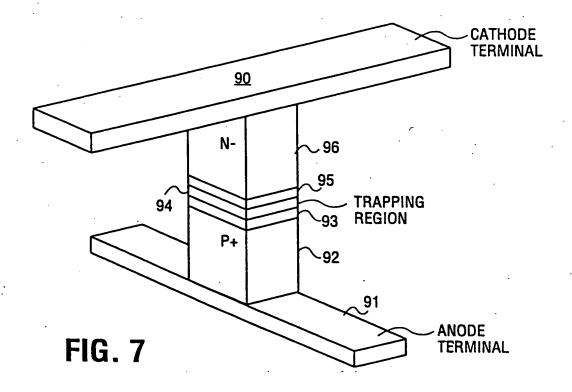
Title: NONVOLATILE MEMORY ON SOI AND COMPOUND SEMICONDUCTOR SUBSTRATES AND METHOD OF FABRICATION

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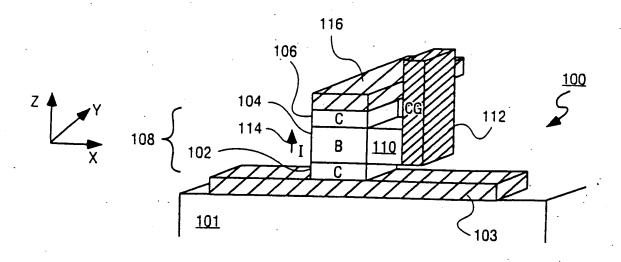
graphical colors (although the colors)

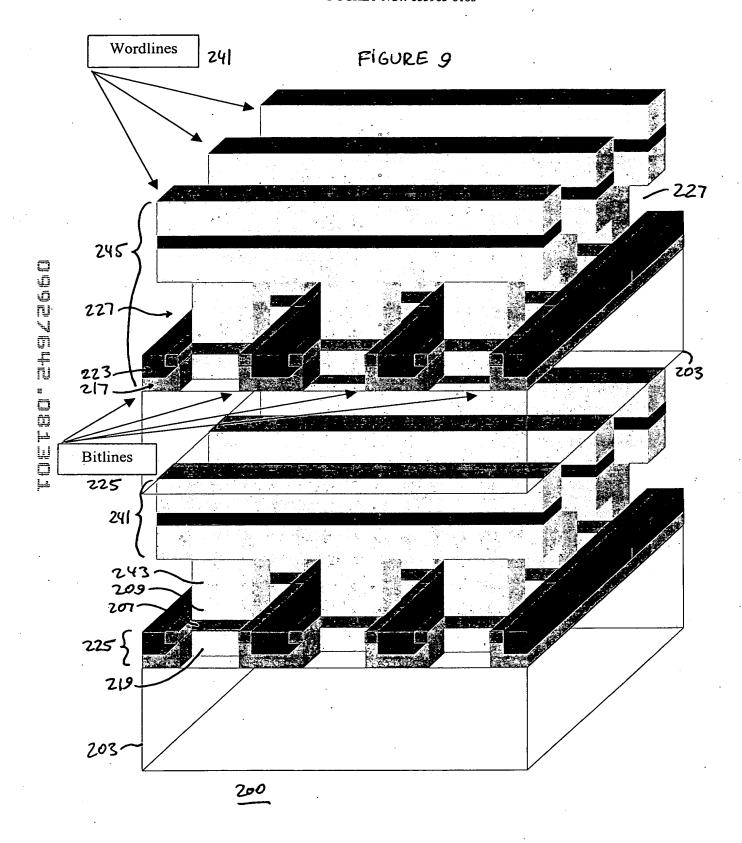




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FIGURE 8





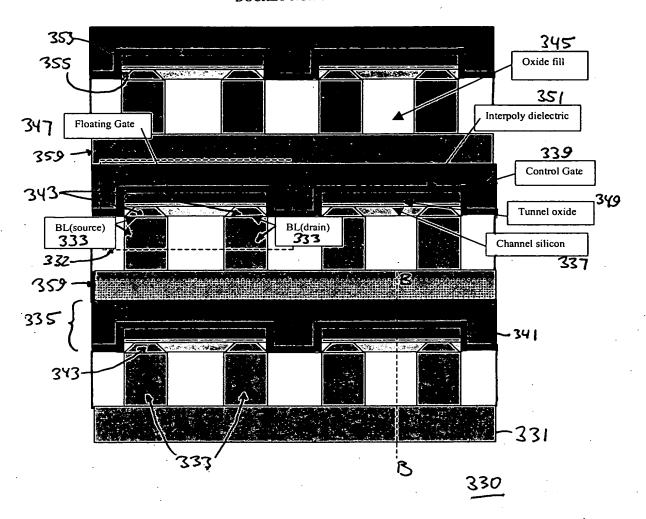


FIGURE 10A

Title: NONVOLATILE MEMORY ON SOI AND COMPOUND SEMICONDUCTOR IBSTRATES AND METHOD OF FABRICATION Inventor(s): Andrew J. WALKER et al. DOCKET NO.: 035905-0103

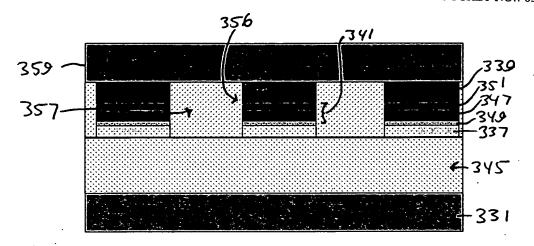
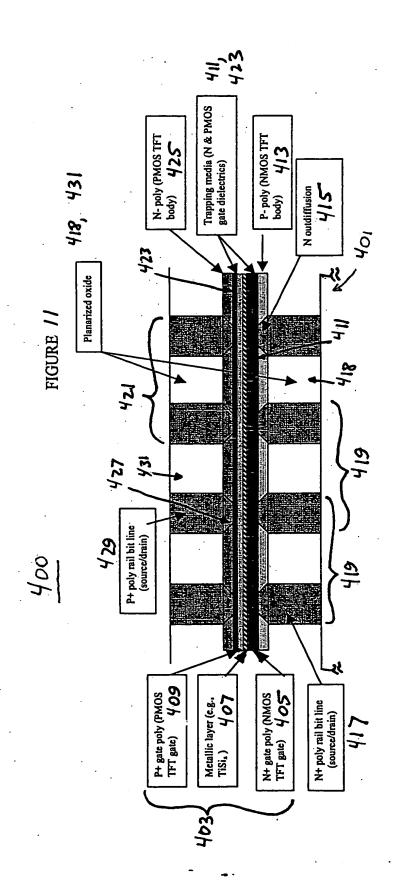
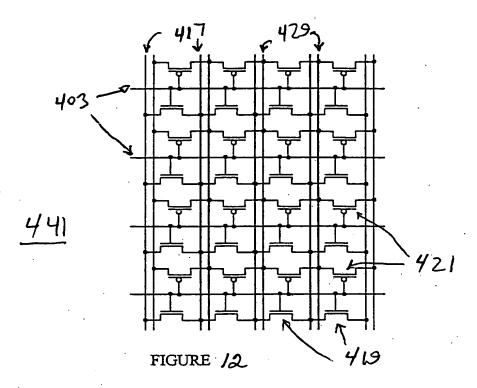


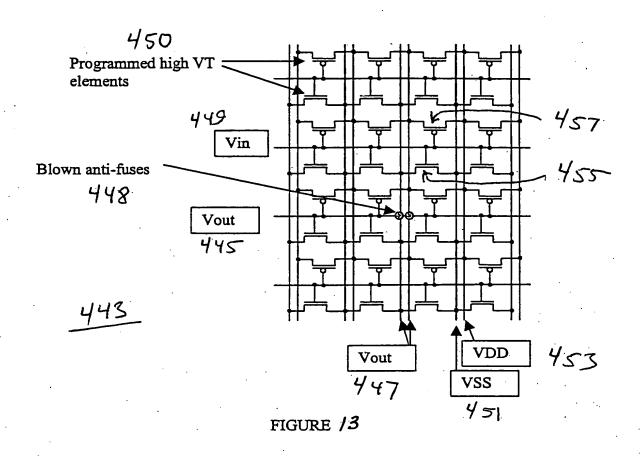
FIGURE 10B

Title: NONVOLATILE MEMORY ON SOI AND COMPOUND SEMICONDUCTOR SUBSTRATES AND METHOD OF FABRICATION
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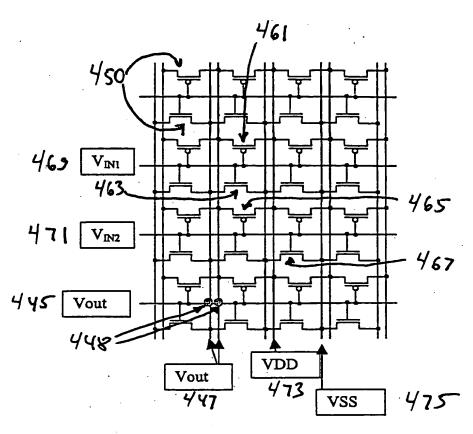


FIGURE 14